

Abstract Submitted  
for the MAR17 Meeting of  
The American Physical Society

**Transport in Ferromagnet/Superconductor Spin Valves**<sup>1</sup> EVAN MOEN, ORIOL T. VALLS, School of Physics and Astronomy, University of Minnesota — We consider transport in realistic Ferromagnet-Superconductor layered nanostructures with a spin-valve structure:  $F_1/N/F_2/S$  where  $F_1$  and  $F_2$  denote the ferromagnets,  $S$  the superconductor, and  $N$  a normal metal spacer usually inserted in these spin-valve devices. These systems exhibit physically intricate proximity effects, including singlet to triplet conversion, which have a large impact on the transport properties and the spin-valve effect. We use a fully self consistent method that ensures that all conservation laws are satisfied. We obtain results for the conductance,  $G$ , of the devices as a function of voltage, for all values of the angle  $\phi$  between the magnetizations of the  $F_1$  and  $F_2$  layers. These calculations are performed for experimentally relevant ranges of layer thicknesses, material properties, and interfacial scattering. We consider also spin currents and spin transfer torques in these structures.

<sup>1</sup>Supported by DOE Grant DE-SC0014467, and the Minnesota Supercomputer Institute

Oriol T. Valls  
Univ of Minn - Minneapolis

Date submitted: 02 Nov 2016

Electronic form version 1.4